The AFB series low noise amplifiers are constructed with MMIC PHEMT devices and provide state-of-the-art broadband performances.

**Application**
- Telecommunication
- Test instrumentation
- Transceiver subassemblies

**Specifications**
- Frequency: 40.0 - 60.0 GHz
- Gain: 30 dB nominal
- Gain flatness: +/- 2.5 dB
- Noise figure: 5.0 dB (typ) / 8.0 dB (max)
- I/O VSWR: 2.0:1 (typ)
- DC bias: 8-12 V / 110 mA nominal
- I/O connectors: V(F) or WR-19 with UG383/ U-M flange
- Operating temperature: -40°C to +50°C

All specifications are subject to change without notice.